



# CBCS SCHEME

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17ELN15/25

## First/Second Semester B.E. Degree Examination, June/July 2018 Basic Electronics

Time: 3 hrs.

Max. Marks: 100

Note: Answer any FIVE full questions, choosing one full question from each module.

### Module-1

- 1 a. Explain the operation of p-n junction diode under forward and reverse bias condition. (08 Marks)
- b. Explain how zener diode can be used as voltage regulator. (05 Marks)
- c. With a neat diagram, explain the output characteristics of a transistor in common base configuration. (07 Marks)

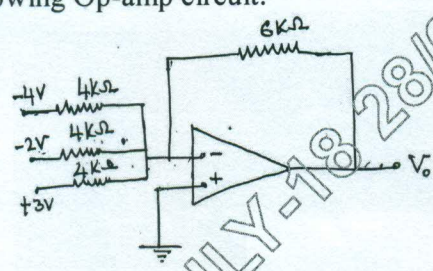
OR

- 2 a. With neat circuit diagram, explain the operation of Centre-tapped full wave rectifier. Draw input and output waveforms. (08 Marks)
- b. Explain the working principle of NPN transistor. (08 Marks)
- c. Explain the relationship between  $\alpha$  and  $\beta$ . Find the values of  $\beta$ ,  $\alpha$  for a transistor has  $I_B = 10\mu A$  and  $I_C = 1mA$ . (04 Marks)

### Module-2

- 3 a. With neat circuit diagram, explain the operation of voltage divider bias circuit with necessary equations. (05 Marks)
- b. What is Op-amp? List the characteristics of an ideal Op-amp. (05 Marks)
- c. Find the output of the following Op-amp circuit. (05 Marks)

Fig. Q3(c)

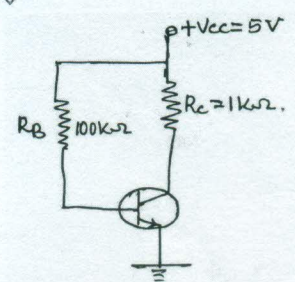


- d. Draw the circuit of Op-amp integrator. Derive the expression of output voltage. (05 Marks)

OR

- 4 a. For the circuit shown in fig. Q4(a), find the Q-point values and draw d.c load line, where  $V_{BE} = 0.7V$  and  $\beta = 50$ . (08 Marks)

Fig. Q4(a)



- b. Define the following terms with respect to Op-amp. (05 Marks)
- c. Draw the circuit of inverting Op-amp. Derive the expression for the voltage gain. (07 Marks)

Important Note : 1. On completing your answers, compulsorily draw diagonal cross lines on the remaining blank pages.  
2. Any revealing of identification, appeal to evaluator and /or equations written eg. 42+8 = 50, will be treated as malpractice.





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**Module-3**

- 5 a. Convert : (08 Marks)
- i)  $(11001.011)_2 = ( )_{10}$
  - ii)  $(186.75)_{10} = ( )_2$
  - iii)  $(64.73)_8 = ( )_{16}$
  - iv)  $(ABCD)_{16} = ( )_2$
- b. Subtract the following using 2's Complement method. (04 Marks)
- i)  $(111001)_2 - (101011)_2$
  - ii)  $(1111)_2 - (1011)_2$
- c. Simplify the following expression and realize using basic gates (04 Marks)
- $$Y = ABC + AB\bar{C} + \bar{A}BC$$
- d. State and prove de - Morgan's theorem using truth table for 2 variable. (04 Marks)

**OR**

- 6 a. Explain full adder circuit with truth table. Realize the circuit for sum and carry using basic gates. Also write the diagram showing full adder using two half adder. (10 Marks)
- b. Implement Ex - OR gate using only NAND gate. (05 Marks)
- c. Simplify and realize the following using only NAND gate. (05 Marks)
- $$Y = A\bar{B}\bar{C} + \bar{A}\bar{B}C + \bar{A}B + \bar{A}\bar{C}$$

**Module-4**

- 7 a. Mention the difference between Latch and Flip flop. (05 Marks)
- b. Define Microcontroller, write important features. (05 Marks)
- c. With a neat block diagram, explain the architecture of 8051 microcontroller. (10 Marks)

**OR**

- 8 a. Write a note on NOR - gate latch. (04 Marks)
- b. Explain the working of clocked RS Flip flop using NAND gates. (06 Marks)
- c. Interface stepper motor to 8051 micro - controller. With a neat block diagram, explain its working principle. (10 Marks)

**Module-5**

- 9 a. With the help of block diagram, explain communication system. (04 Marks)
- b. Define Amplitude modulation. Derive Mathematical expression for the same. Draw waveforms. (08 Marks)
- c. Explain the construction and principle of operation of LVDT. (08 Marks)

**OR**

- 10 a. List the difference between AM and FM. (04 Marks)
- b. Explain Frequency modulation, with neat waveform. (08 Marks)
- c. Briefly explain the working of thermistor. Mention its applications. (08 Marks)

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